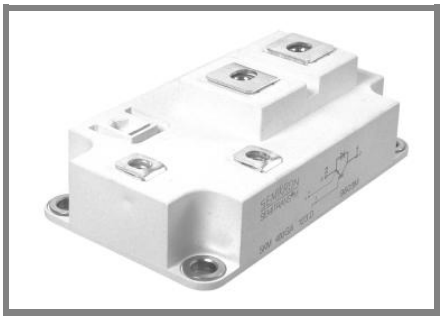
SKM 600GA126D



SEMITRANS® 4

Trench IGBT Modules

SKM 600GA126D

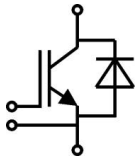
Preliminary Data

Features

- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability, self limiting to 6 x I_C

Typical Applications

- AC inverter drives
- UPS
- Electronic welders



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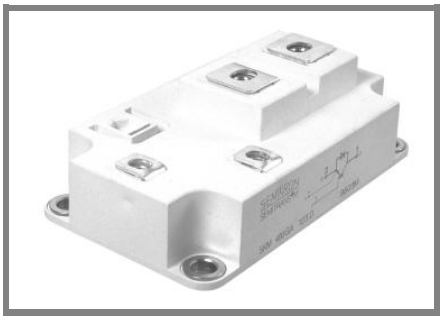
Absolute Maximum Ratings	T_{case} = 25°C, unless otherwise specified			
Symbol	**Conditions**		**Values**	**Units**
IGBT				
V_{CES}	T_j = 25 °C		1200	V
I_C	T_j = 150 °C	T_c = 25 °C	660	A
		T_c = 80 °C	460	A
I_{CRM}	I_{CRM}=2xI_{Cnom}		800	A
V_{GES}			± 20	V
t_{psc}	V_{CC} = 600 V; $V_{GE} \leq$ 20 V; V_{CES} < 1200 V	T_j = 125 °C	10	µs
Inverse Diode				
I_F	T_j = 150 °C	T_c = 25 °C	490	A
		T_c = 80 °C	340	A
I_{FRM}	I_{FRM}=2xI_{Fnom}		800	A
I_{FSM}	t_p = 10 ms; sin.	T_j = 150 °C	2900	A
Module				
$I_{t(RMS)}$			500	A
T_{vj}			-40 ...+ 150	°C
T_{stg}			-40 ... + 125	°C
V_{isol}	AC, 1 min.		4000	V

Characteristics	T_{case} = 25°C, unless otherwise specified					
Symbol	**Conditions**		**min.**	**typ.**	**max.**	**Units**
IGBT						
$V_{GE(th)}$	V_{GE} = V_{CE}, I_C = 16 mA		5	5,8	6,5	V
I_{CES}	V_{GE} = 0 V, V_{CE} = V_{CES}	T_j = 25 °C		0,2	0,6	mA
		T_j = 125 °C				mA
V_{CE0}		T_j = 25 °C		1	1,2	V
		T_j = 125 °C		0,9	1,1	V
r_{CE}	V_{GE} = 15 V	T_j = 25°C		1,8	2,4	mΩ
		T_j = 125°C		2,8	3,4	mΩ
$V_{CE(sat)}$	I_{Cnom} = 400 A, V_{GE} = 15 V	T_j = 25°C$_{chiplev.}$		1,7	2,15	V
		T_j = 125°C$_{chiplev.}$		2	2,45	V
C_{ies}	V_{CE} = 25, V_{GE} = 0 V	f = 1 MHz		29		nF
C_{oes}				1,5		nF
C_{res}				1,3		nF
Q_G	V_{GE} = -8V - +20V			3600		nC
R_{Gint}	T_j = °C			1,88		Ω
$t_{d(on)}$	R_{Gon} = 2 Ω	V_{CC} = 600V		330		ns
t_r		I_{Cnom}= 400A		65		ns
E_{on}		T_j = 125 °C		39		mJ
$t_{d(off)}$	R_{Goff} = 2 Ω	V_{GE} = ± 15V		630		ns
t_f				130		ns
E_{off}				64		mJ
$R_{th(j-c)}$	per IGBT				0,055	K/W

SKM 600GA126D



SEMITRANS® 4

Trench IGBT Modules

SKM 600GA126D

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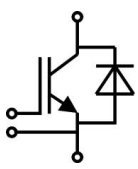

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Characteristics						
Symbol	**Conditions**		**min.**	**typ.**	**max.**	**Units**
Inverse diode						
$V_F = V_{EC}$	I_{Fnom} = 400 A; V_{GE} = 0 V	T_j = 25 °$C_{chiplev.}$		1,6	1,8	V
		T_j = 125 °$C_{chiplev.}$		1,6	1,8	V
V_{F0}		T_j = 25 °C		1	1,1	V
		T_j = 125 °C		0,8	0,9	V
r_F		T_j = 25 °C		1,5	1,8	mΩ
		T_j = 125 °C		2	2,3	mΩ
I_{RRM}	I_{Fnom} = 400 A	T_j = 125 °C		350		A
Q_{rr}	di/dt = 5800 A/µs			87		µC
E_{rr}	V_{GE} = -15 V; V_{CC} = 600 V					mJ
$R_{th(j-c)D}$	per diode				0,125	K/W
Module						
L_{CE}				15	20	nH
$R_{CC'+EE'}$	res., terminal-chip	T_{case}= 25 °C		0,18		mΩ
		T_{case}= 125 °C		0,22		mΩ
$R_{th(c-s)}$	per module				0,038	K/W
M_s	to heat sink M6		3		5	Nm
M_t	to terminals M6 (M4)		2,5 (1,1)		5 (2)	Nm
w					330	g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

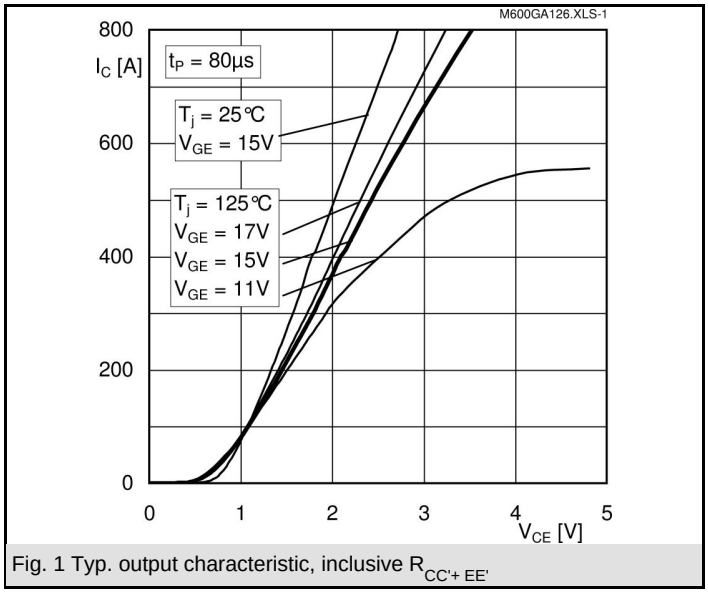

Fig. 1 Typ. output characteristic, inclusive $R_{CC'+EE'}$

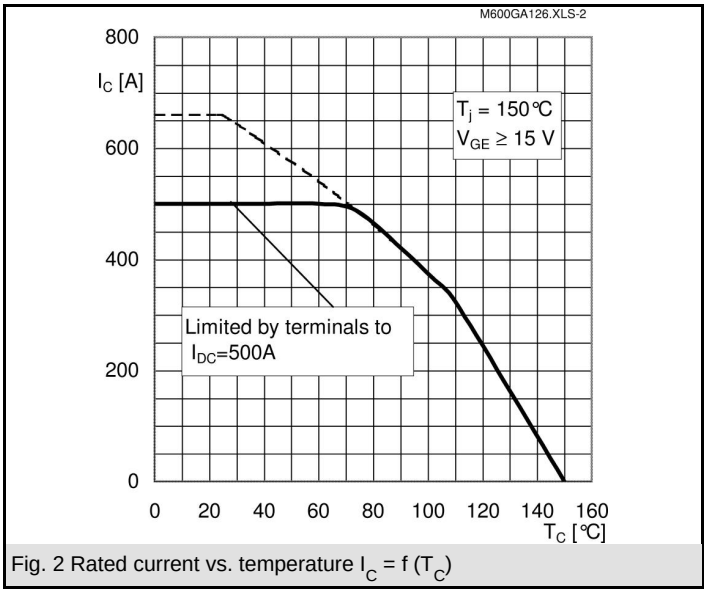

Fig. 2 Rated current vs. temperature $I_C = f(T_C)$

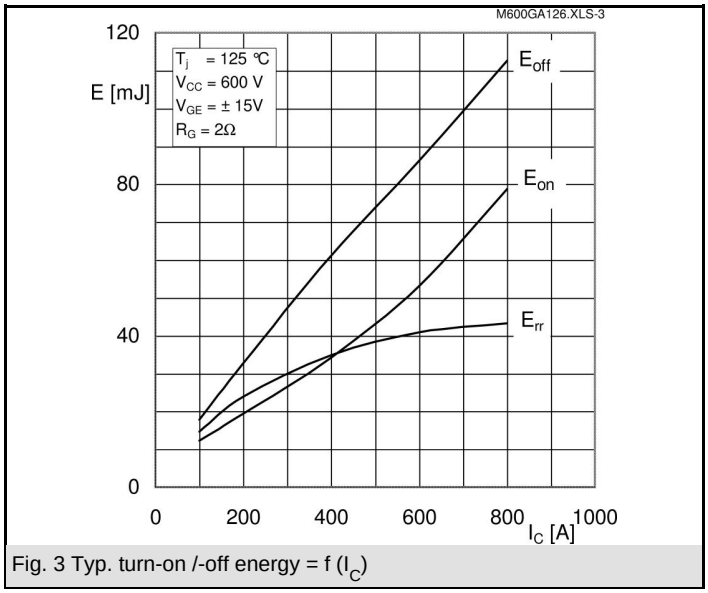

Fig. 3 Typ. turn-on /-off energy = f (I_C)

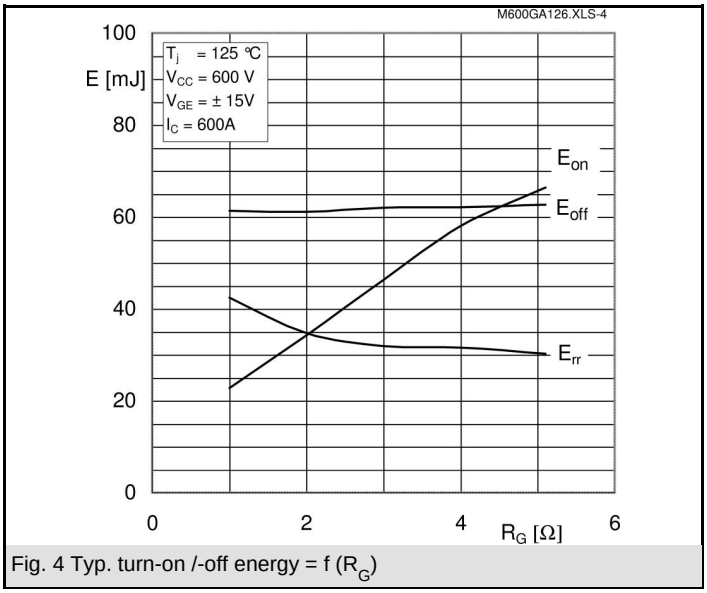

Fig. 4 Typ. turn-on /-off energy = f (R_G)

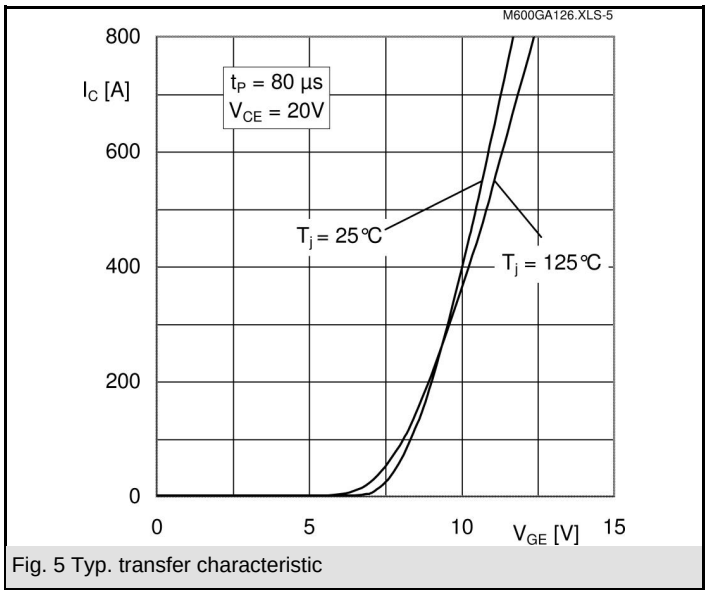

Fig. 5 Typ. transfer characteristic

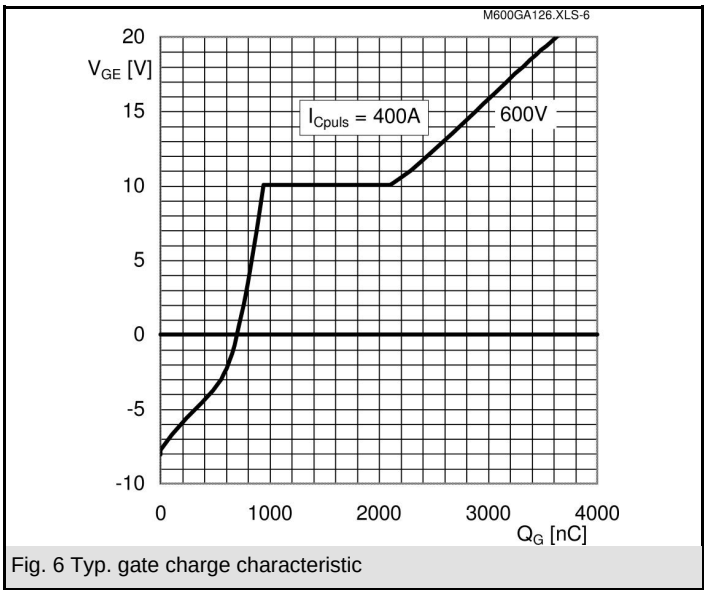

Fig. 6 Typ. gate charge characteristic

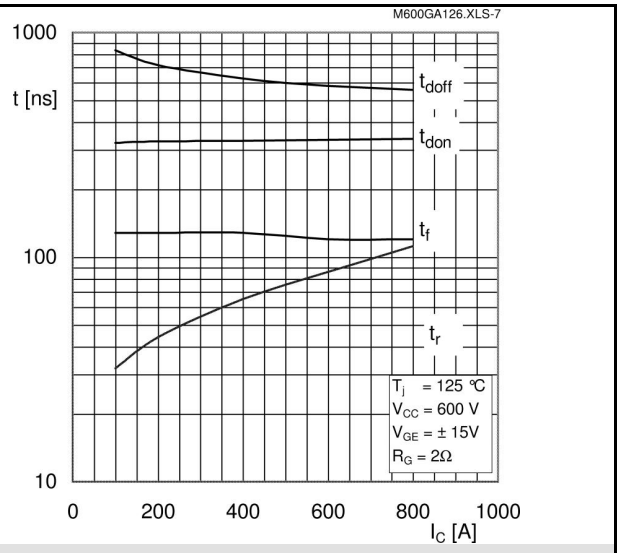

Fig. 7 Typ. switching times vs. I_C

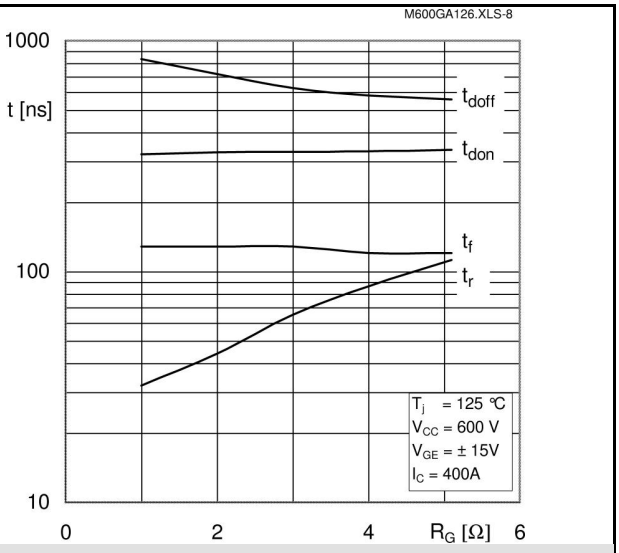

Fig. 8 Typ. switching times vs. gate resistor R_G

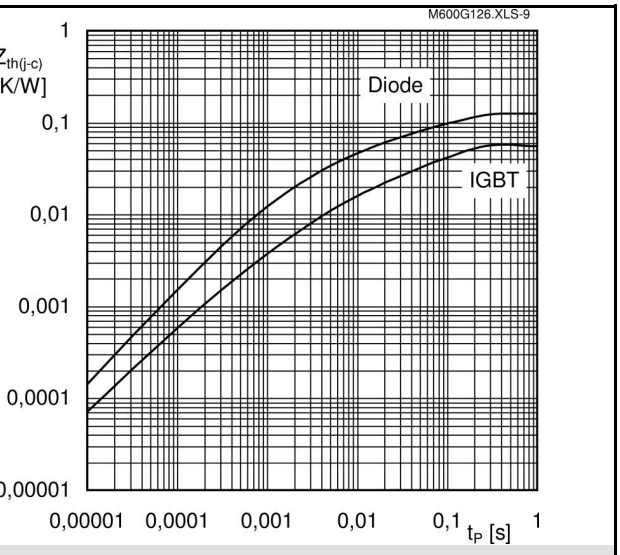

Fig. 9 Transient thermal impedance

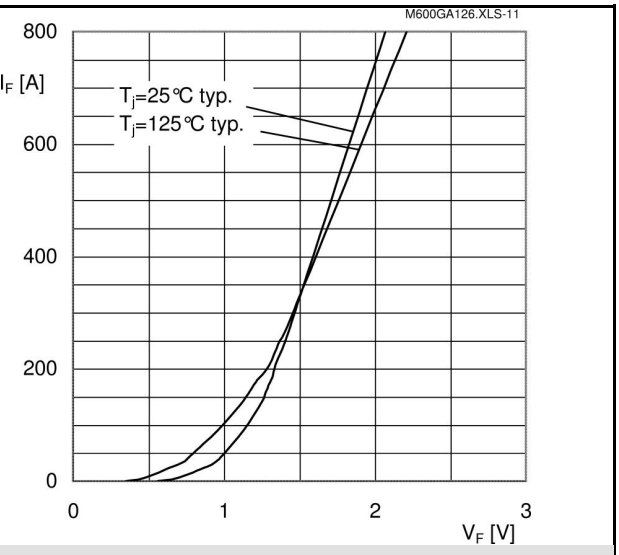

Fig. 10 CAL diode forward characteristic

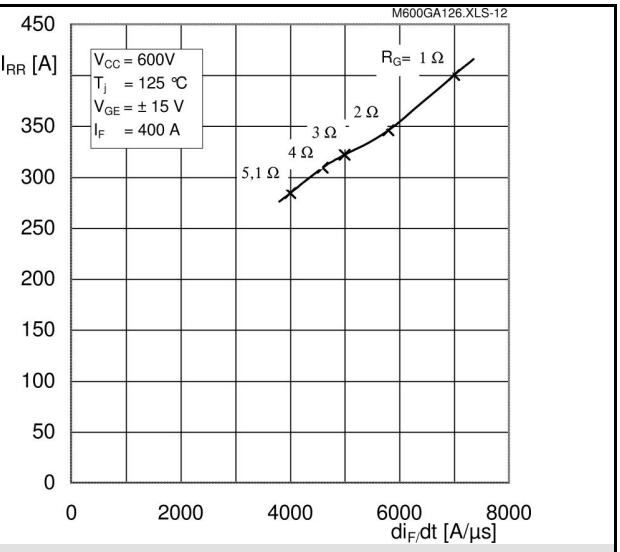

Fig. 11 Typ. CAL diode peak reverse recovery current

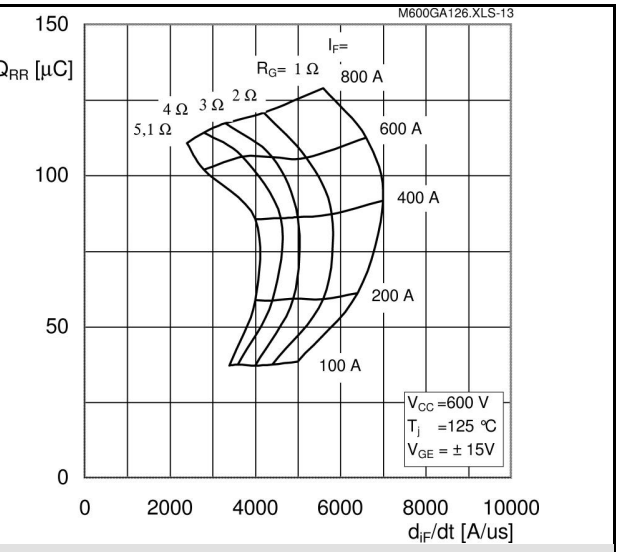

Fig. 12 Typ. CAL diode peak reverse recovery charge

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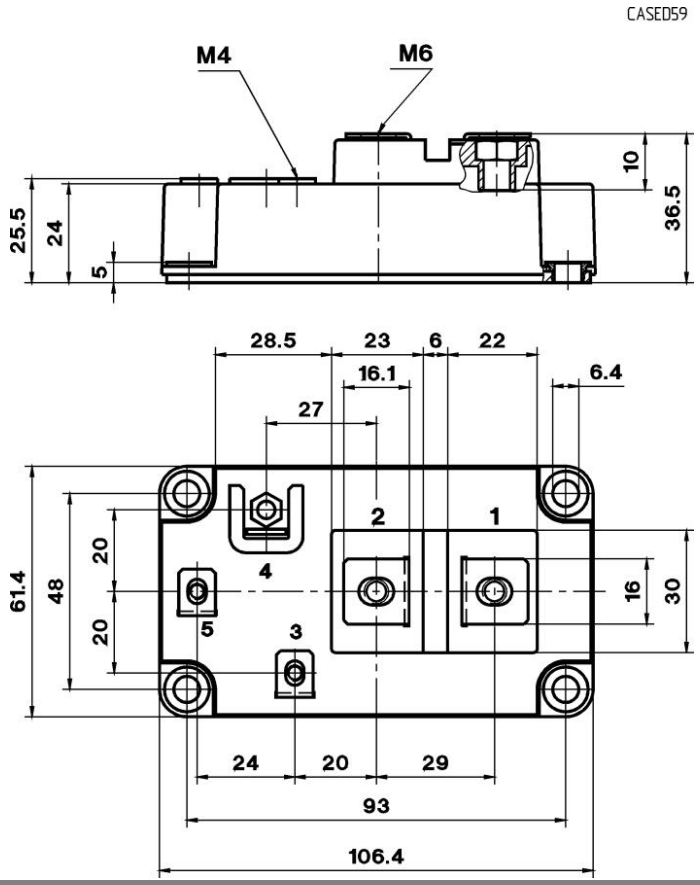
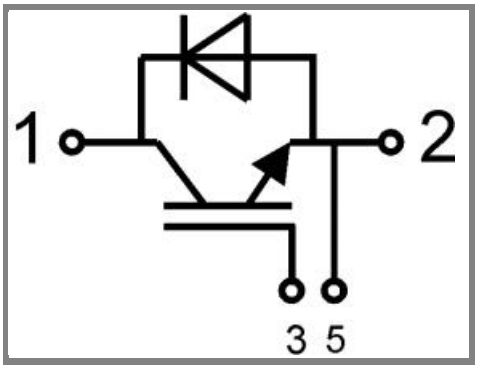


Case D 59



GA Case D59

